

Description

Passivated high commutation triacs in a plastic envelope intended for use in circuits where high static and dynamic dV/dt and high dI/dt can occur. These devices will commute the full rated ms current at the maximum rated junction temperature without the aid of a snubber.

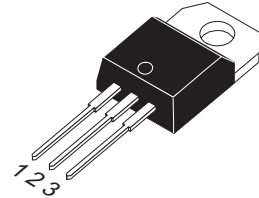
Features

- Blocking voltage to 600 V
- On-state RMS current to 20 A

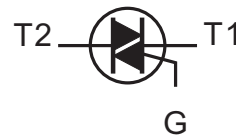
Applications

- Motor control
- Industrial and domestic lighting
- Heating
- Static switching

Simplified outline TO-220AB



Symbol



Pin	Description
1	Main terminal 1 (T1)
2	Main terminal 2 (T2)
3	gate (G)
TAB	Main terminal 2 (T2)

SYMBOL	PARAMETER	Value	Unit
V_{DRM}	Repetitive peak off-state voltages	600	V
$I_T (RMS)$	RMS on-state current (full sine wave)	20	A
I_{TSM}	Non-repetitive peak on-state current (full cycle, T_j initial=25°C)	200	A

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$R_{th(j-c)}$	Junction to case(AC)		-	1.3	-	°C/W
$R_{th(j-a)}$	Junction to ambient		-	60	-	°C/W

Limiting values in accordance with the Maximum system(IEC 134)

SYMBOL	PARAMETER	CONDITIONS		MAX	Value	UNIT
V_{DRM}	Repetitive peak off-state Voltages	$T_j=125^{\circ}C$		-	600	V
$I_{T(RMS)}$	RMS on-state current	360° conduction angle $T_c=90^{\circ}C$		-	20	A
I_{TSM}	Non repetitive surge peak on-state current	full cycle, T_j initial= 25 °C	$t_p=8.3ms$	-	210	A
			$t_p=10ms$	-	200	A
I^2t	I^2t value	$T_p=10ms$		-	200	A ² S
DI/dt	Critical rate of rise of on-state current	Gate supply: $I_G=500mA$ $dI_G/dt=1A/us$	Repetitive F=50Hz	-	20	A/μs
			Non repetitive	-	100	
I_{DRM}	V_{DRM} rated	$T_j=25^{\circ}C$		0.01	-	mA
I_{RRM}	V_{RRM} rated	$T_j=125^{\circ}C$		3	-	mA
T_l	Maximum lead soldering temperature during 10s at 4.5mm form case			-	260	°C
T_{stg}	Storage and operating junction temperature range			-40	150	°C
T_j	Storage and operating junction temperature range			-40	125	°C

 $T_j = 25^{\circ}C$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT	
Static characteristics							
I_{GT}	$V_D=12V(DC); R_L=33\Omega$	$T_j=25^{\circ}C$	I-II-III	2	-	50	mA
V_{GT}			I-II-III	-	-	1.5	V
I_L	$I_G=1.2 I_{GT}$	$T_j=25^{\circ}C$	I-III	-	50	-	mA
			II	-	90	-	
			I-II-III	-	-	-	
I_H	$I_T=500mA$ Gate open	$T_j=25^{\circ}C$	-	-	75	mA	
V_{GD}	$V_D=V_{DRM}$ $R_L=3.3K\Omega$	$T_j=125^{\circ}C$	I-II-III	0.2	-	-	V
dV/dt	$V_D=67\%V_{DRM}$ gate open;	$T_j=125^{\circ}C$		500	750	-	V/μs
(dv/dt)c	Without snubber	$T_j=125^{\circ}C$		18	36	-	A/ms

Dynamic Characteristics

$V_{TM}(2)$	$I_{TM}=28A$ $t_p=380us$	$T_j=25^{\circ}C$		-	-	1.70	V
tgt	$V_D=V_{DRM}$ $I_G=500mA$ $dI_G/dt=3A/us$	$T_j=25^{\circ}C$	I-II-III	-	2	-	μs

Description

Fig. 1: Maximum RMS power dissipation versus RMS on-state current ($F = 50\text{Hz}$). (Curves are cut off by $(di/dt)_c$ limitation)

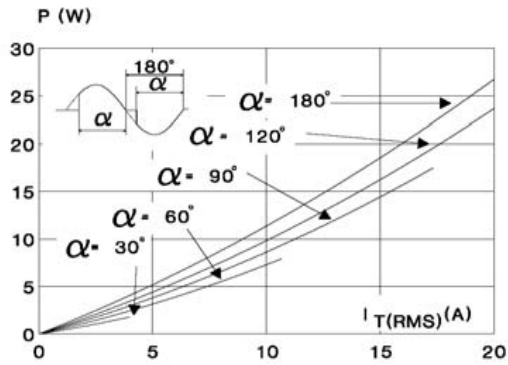


Fig. 2: Correlation between maximum RMS power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact (BTA).

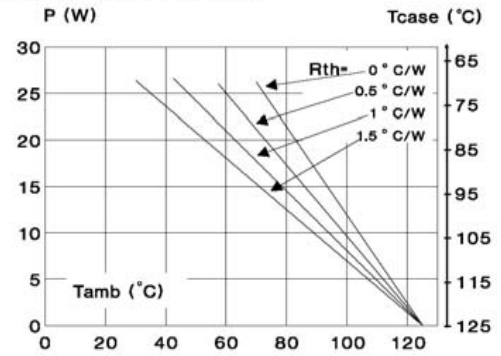


Fig. 3: Correlation between maximum RMS power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact (BTB).

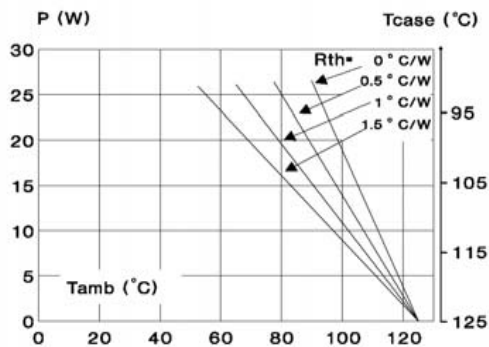


Fig. 4: RMS on-state current versus case temperature.

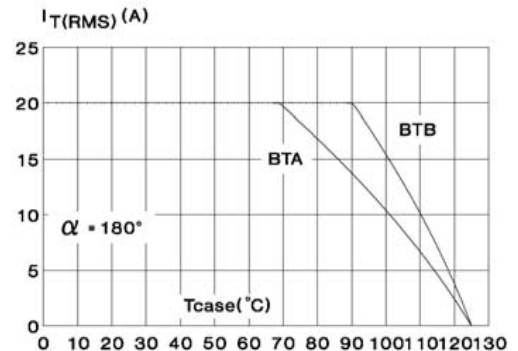


Fig. 5: Relative variation of thermal impedance versus pulse duration.

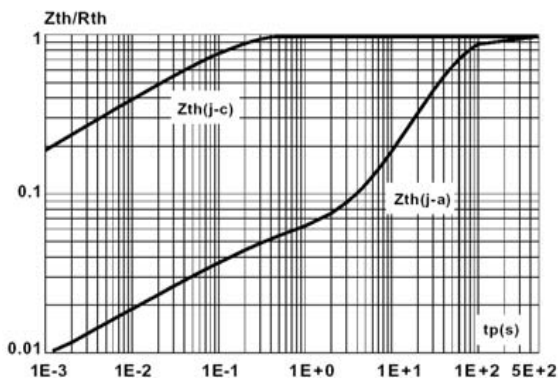
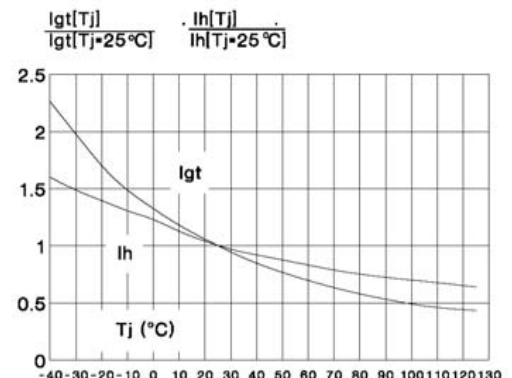


Fig. 6: Relative variation of gate trigger current and holding current versus junction temperature.



Description

Fig. 7: Non repetitive surge peak on-state current versus number of cycles.

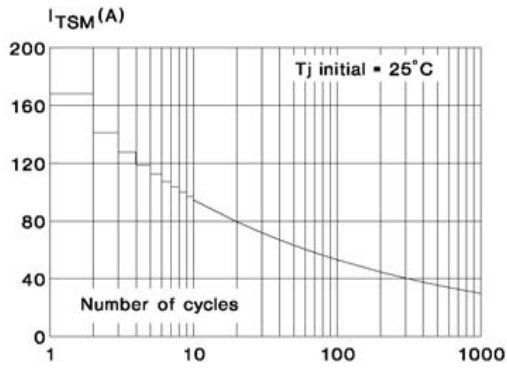


Fig. 8: Non repetitive surge peak on-state current for a sinusoidal pulse with width: $t \leq 10\text{ms}$, and corresponding value of I^2t .

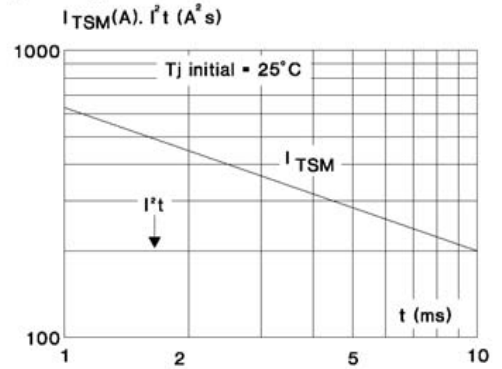
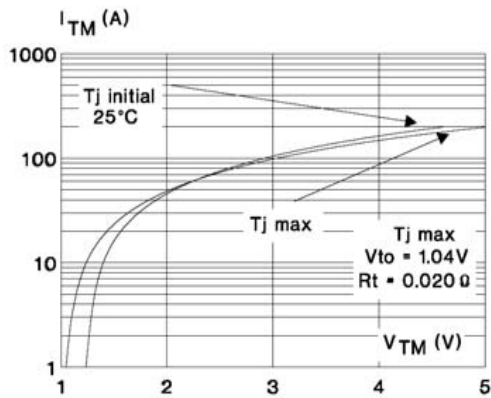
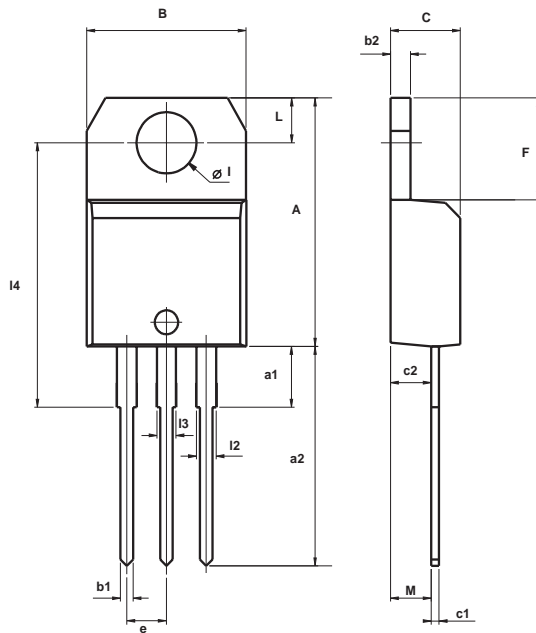


Fig. 9: On-state characteristics (maximum values).



Package Mechanical Data
TO-220AB (Plastic)


REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
I	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
I3	1.14		1.70	0.044		0.066
M		2.60			0.102	